

产业基础创新发展目录

（2021年版）

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● 编制说明 ●

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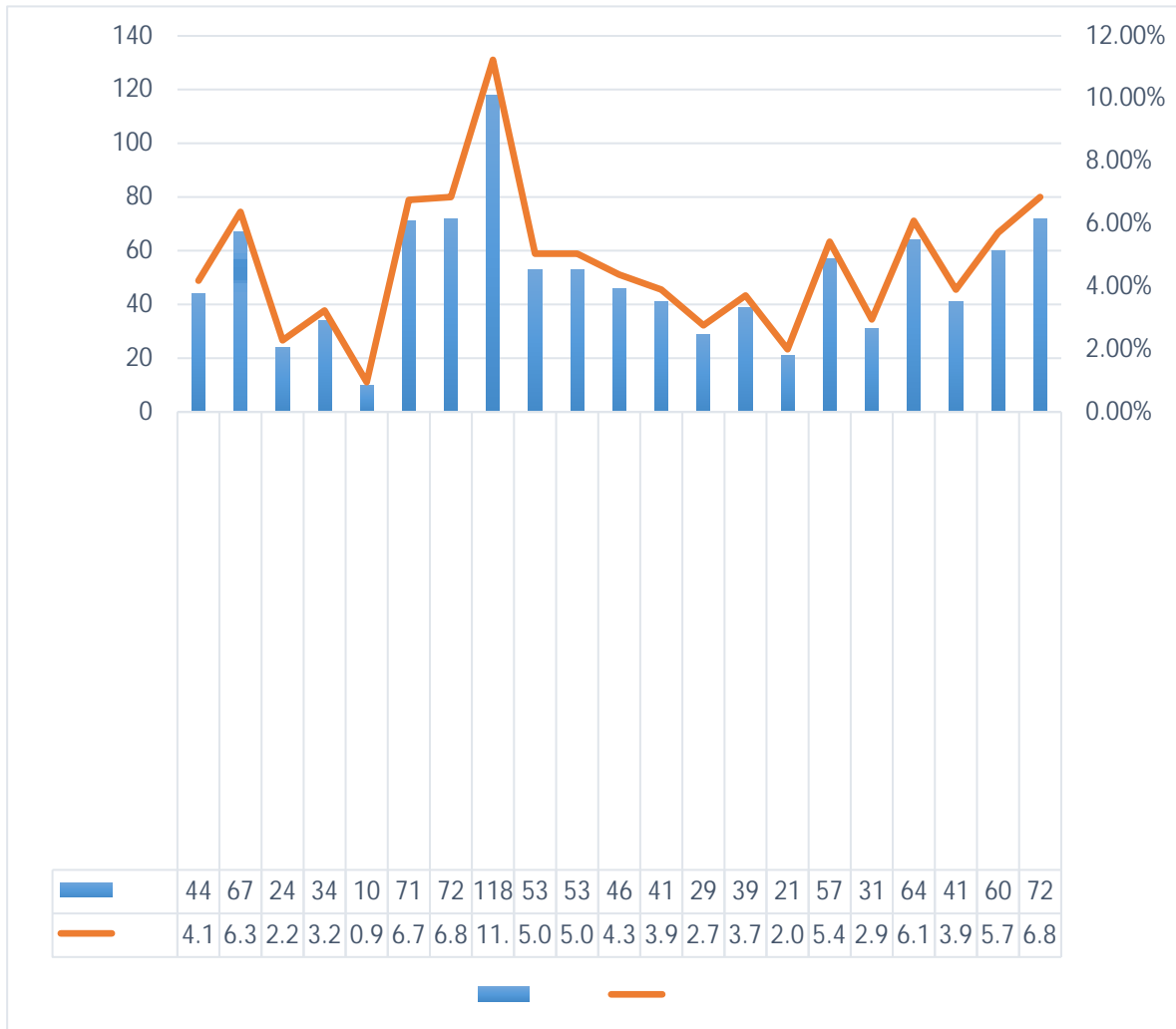
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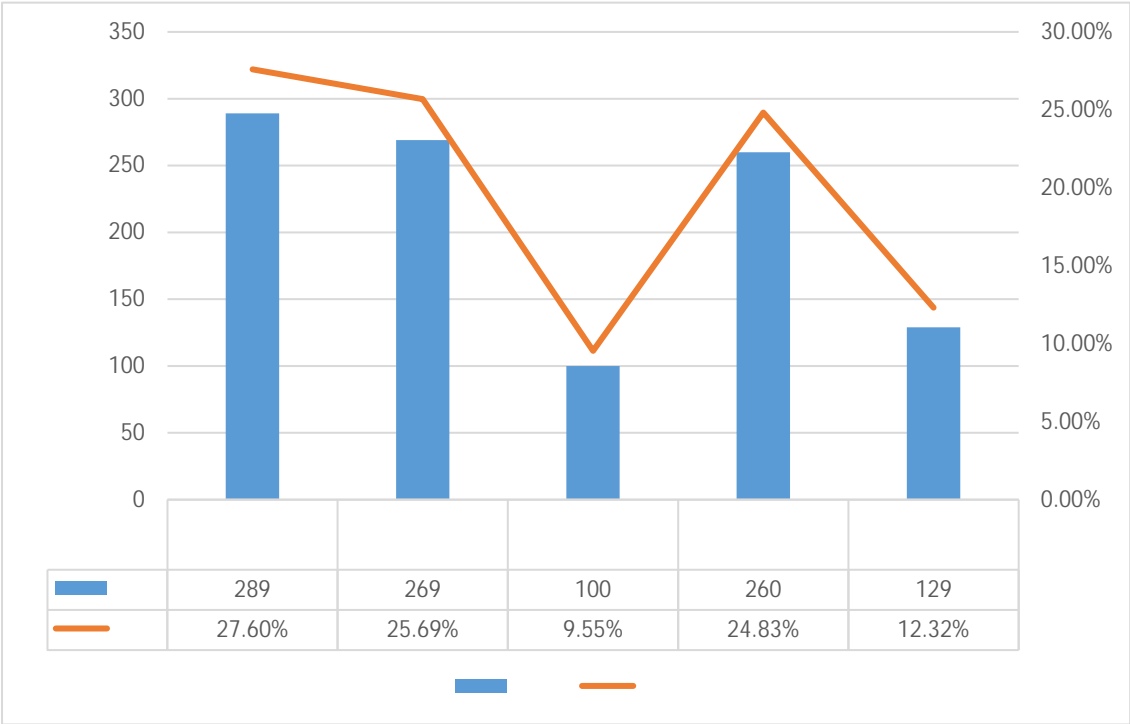
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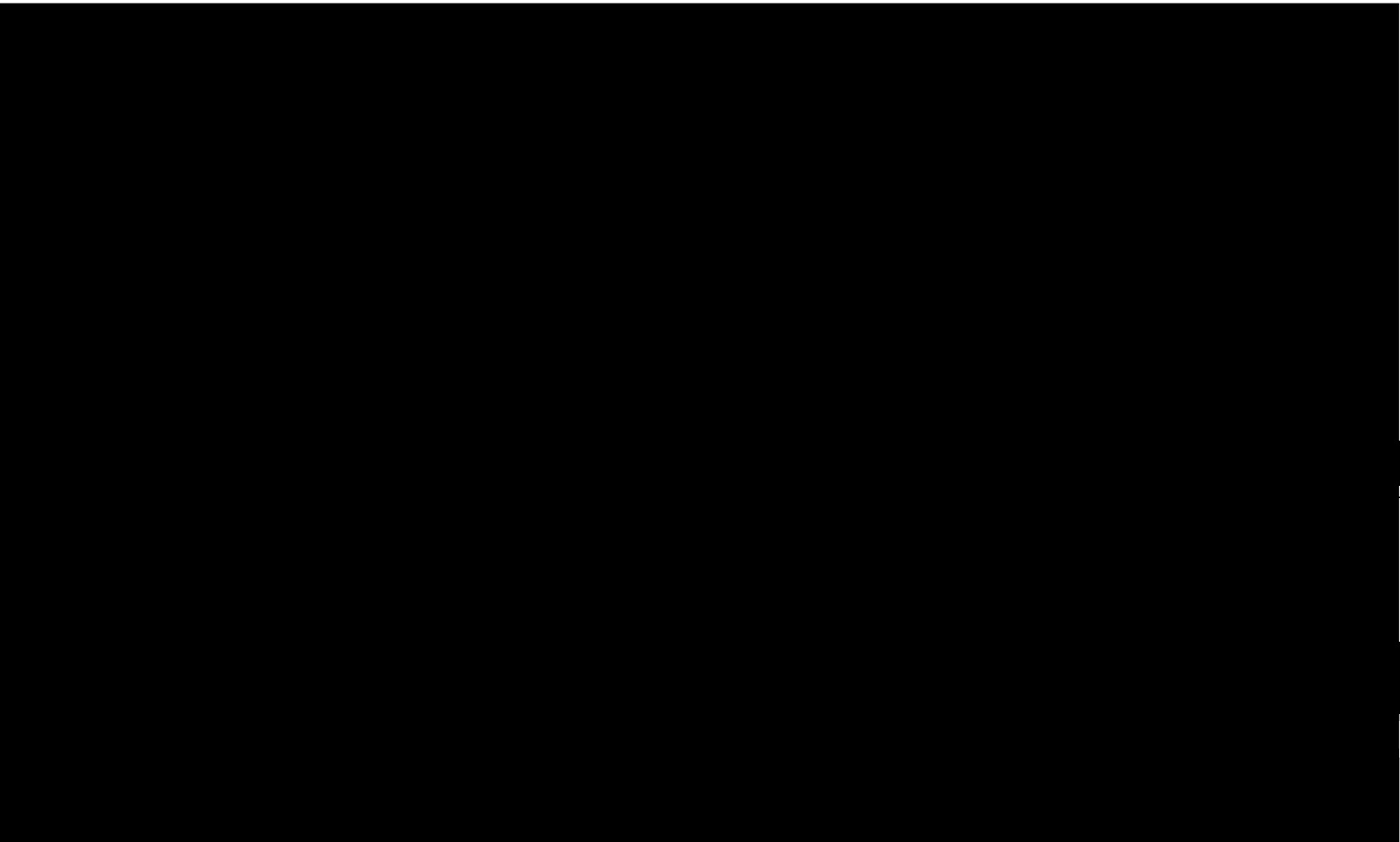
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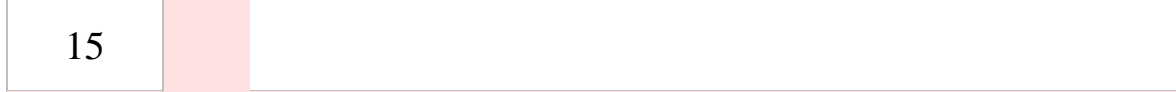
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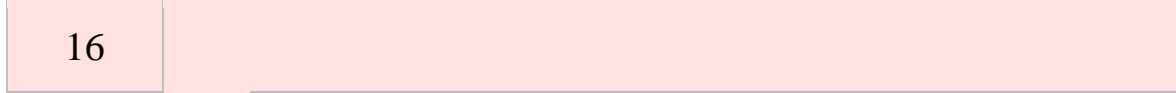
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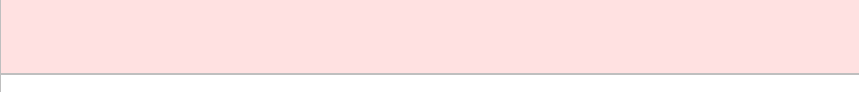
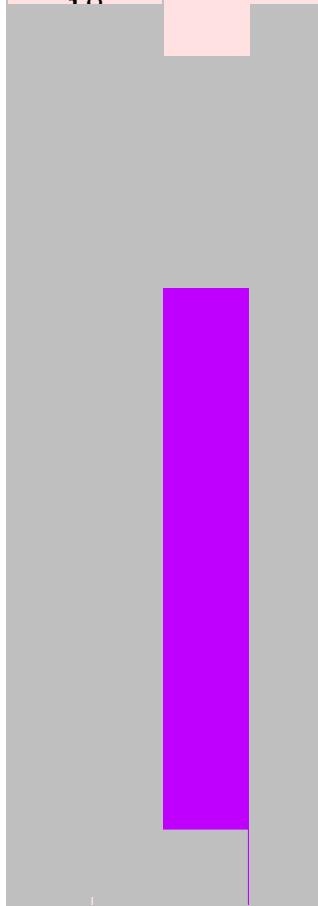
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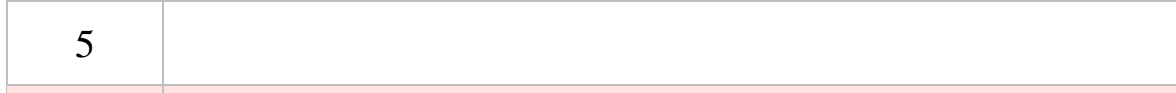
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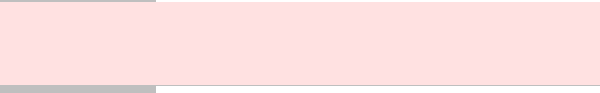
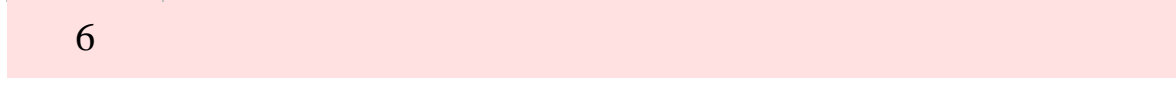
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● 编制组名单 ●

在编制过程中，广泛征集了企业、高校及科研院所、行业协会、专业学会的意见，在此一并感谢。

● 国家产业基础专家委员会简介 ●

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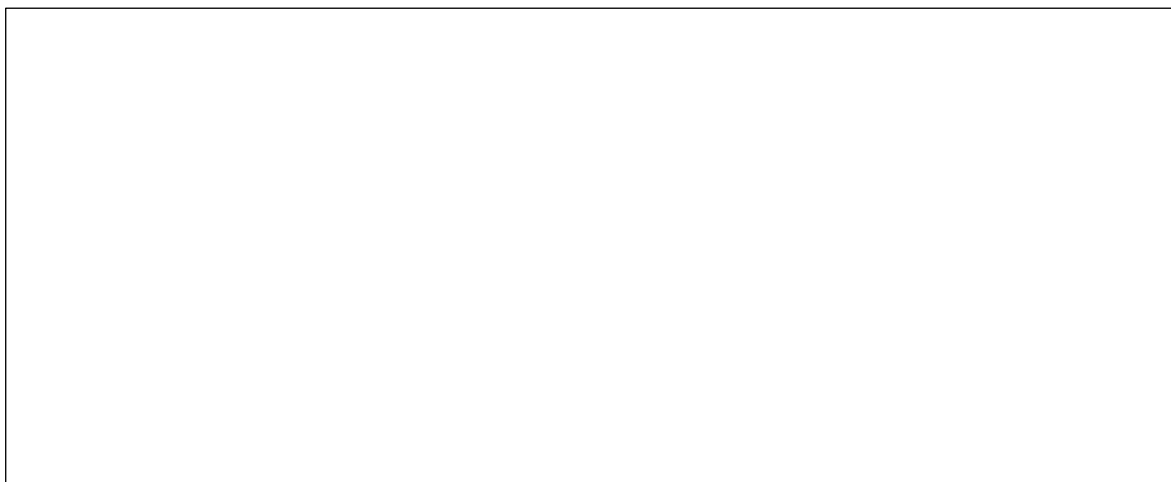
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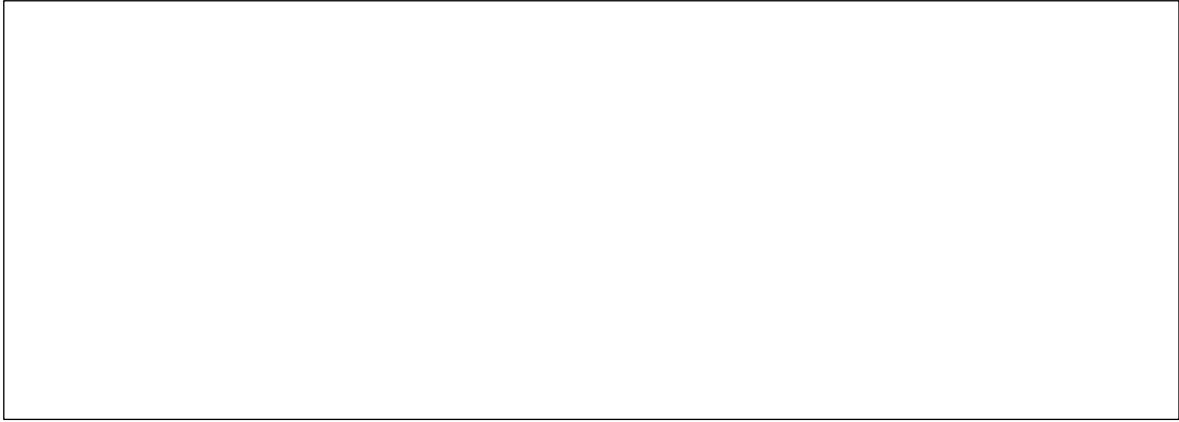
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010-59300248 yxy@cae.cn 18611963686

—● 国家产业基础专家委员会委员名单 ●—

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